5/15/2018

Control System-I Lab - MCT-333L Lab Reports



Submitted By:

Muhammad Waqar Nawaz (2015-MC-167)

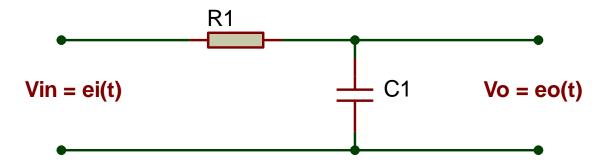
Submitted To:

Engr. Abdullah Tahir

First Order System

Objectives:

1. To model the following circuit and also select the components for maximum Ts = 0.8s and maximum Tr = 0.06s



Theory:

Modeling:

$$R\frac{dq}{dt}(t) + \frac{1}{c}q(t) = e_i(t)$$

 $q(t)=Ce_o(t)$

$$RCSE_{o}(s) + E_{o}(s) = E_{i}(s)$$

$$\frac{\text{Eo}(s)}{\text{Ei}(s)} = \frac{1}{RCS+1}$$

$$\frac{\text{Eo(s)}}{\text{Ei(s)}} = \frac{\frac{1}{RC}}{(S + \frac{1}{RC})}$$

Compare it with General T.F of 1st order equation T.F = $\frac{a}{S+a}$

$$a = 1/RC$$

$$Ts = 3.91/a$$

$$Tr = 2.195/a$$

Required:

$$a = 3.91/0.8$$

$$a = 1/RC = 4.8875$$

$$a = 2.195/0.06$$

$$a = 1/RC = 36.58$$

4.8875 < a < 36.58

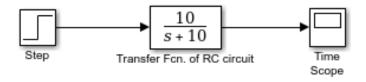
Let a = 10 then,

$$R = 1 \text{K(ohm)}$$

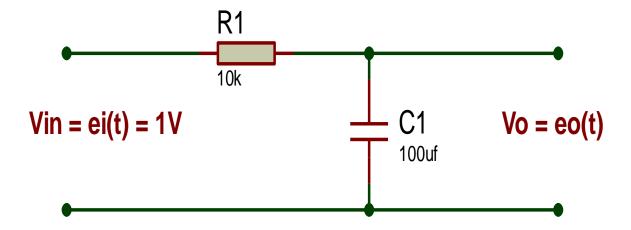
$$C = 100 \times 10^{-6} f$$

$$Step input = e_i(t) = 1 \text{V}$$

Simulation:

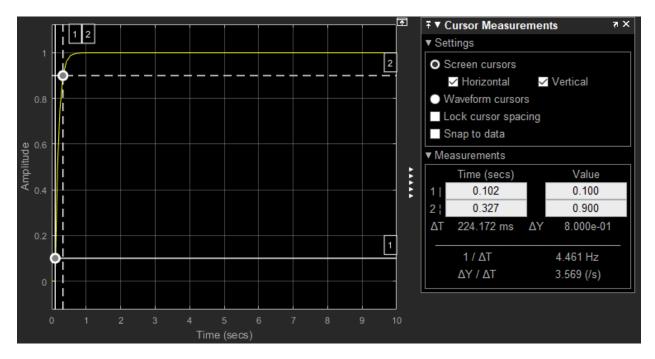


Hardware Schematic:



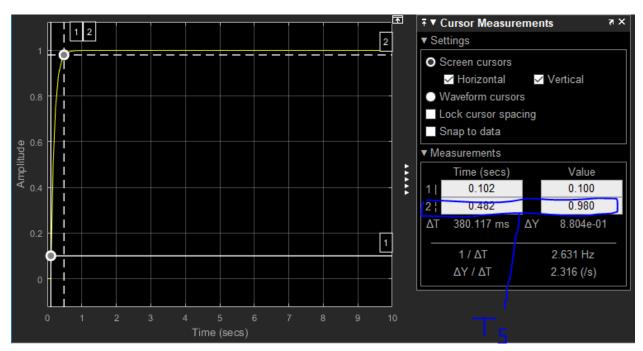
Result:

Rise Time (Tr):



Tr = 0.327 - 0.102 = 0.225s

Settling Time (Ts):



Control System-I Lab - MCT-333L | Spring

2018

Ts = 0.482s

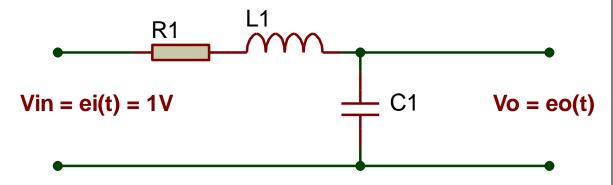
Comments:

System settling time less than 0.8s.

Second Order System

Objectives:

- 1. To model the following circuit and also select the components for
 - Under-damped
 - Over damped
 - Critically damped
 - Un-damped



Theory:

Modeling:

$$\mathrm{L}\left(\mathrm{d}^{2}q/\mathrm{d}t^{2}\right)\left(t\right)\mathrm{R}\frac{dq}{dt}\left(t\right)+\frac{1}{c}q\left(t\right)=\mathrm{e}_{\mathrm{i}}(t)$$

 $q(t)=Ce_o(t)$

$$LCS^{2}E_{o}(s) + RCSE_{o}(s) + E_{o}(s) = E_{i}(s)$$

$$\frac{\text{Eo(s)}}{\text{Ei(s)}} = \frac{1}{(\textit{LCS+RC})\textit{S}+1}$$

$$\frac{\text{Eo(s)}}{\text{Ei(s)}} = \frac{\frac{1}{LC}}{(\left(S + \frac{R}{L}\right)s + \frac{1}{LC})}$$

Compare it with General T.F of 2^{st} order equation T.F = $\omega_n^2 / (s^2 + 2\rho \omega_n s + \omega_n^2)$

$$a = R/L = 2\rho\omega_n$$

$$\rho = a/(2\omega_n)$$

$$b = 1/(LC) = \omega_n^2$$

Required:

Under-damped

$$0 < \rho < 1$$

R = 40 (ohm); C = 510x10-6F; L= 1H; ei= 1volt

$$\rho = 0.452$$

Over damped

$$\rho < 0$$

R = 100 (ohm); C = 510x10-6F; L= 1H; ei= 1volt

$$\rho = 1.129$$

Critically damped

$$\rho = 1$$

R = 885.6 (ohm); C = 510x10-6F; L = 1H; ei = 1volt

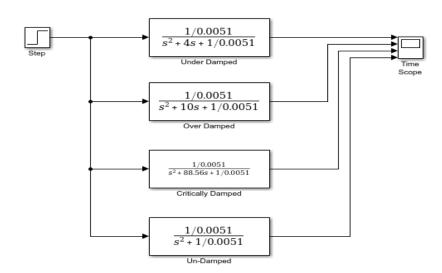
$$\rho \approx 1$$

Un-damped

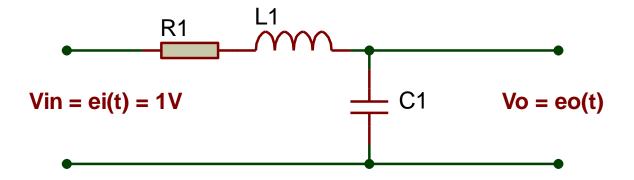
$$\rho = 0$$

R = 0 (ohm); C = 510x10-6F; L = 1H; ei = 1volt

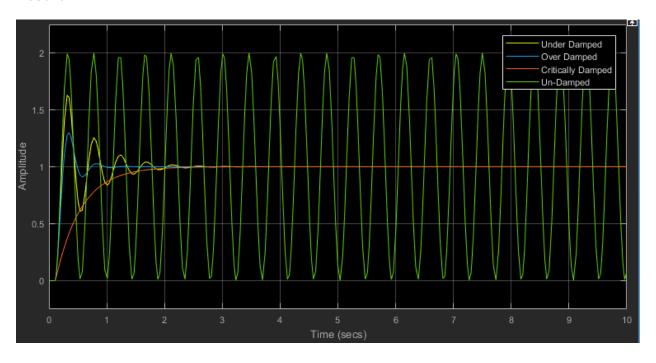
Simulation:



Hardware Schematic:



Result:



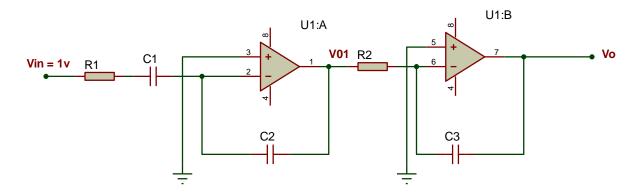
Comments:

• In 1st order system value starts from zero of the graph but in Over damped system value starts after zero of the graph.

Operational Amplifier

Objectives:

1. Design the following circuit for maximum OS% = 10%, maximum Tp = 0.2s and maximum Ts = 0.6s



Theory:

Modeling:

$$\begin{split} \frac{v_{o1}}{v_{in}} &= -\frac{z_{2}(s)}{z_{1}(s)} \\ Z_{1}(s) &= (1/C_{1}S) + R_{1} = (R_{1}C_{1}S + 1) / (C_{1}S) \\ Z_{2}(s) &= (1/C_{2}S) \\ \\ \frac{v_{o1}}{v_{in}} &= -C_{1} / (R_{1}C_{2}C_{1}S + C_{2}) \\ \\ \frac{v_{o}}{v_{o1}} &= -\frac{z_{4}(s)}{z_{3}(s)} \\ \\ \frac{v_{o}}{v_{o1}} &= -1 / (R_{2}C_{3}S) \\ \\ \frac{v_{o}}{v_{in}} &= ((1/R_{1}R_{2}C_{2}C_{3}) / (S^{2} + (1/(R_{1}C_{1})))) \end{split}$$

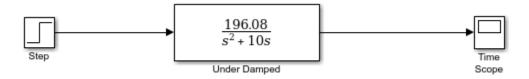
Required:

Under-damped

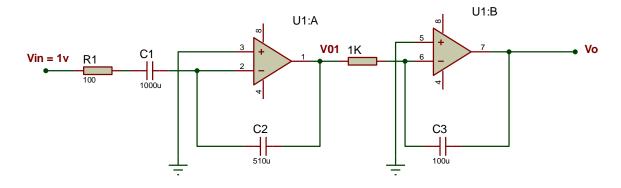
$$0 < \rho < 1$$

 $R_1 = 100 \text{ (ohm)}; R_2 = 1000 \text{ (ohm)}; C_2 = 510x10-6F; C_3 = 100uF; C_1 = 1000uF; ei=1volt$

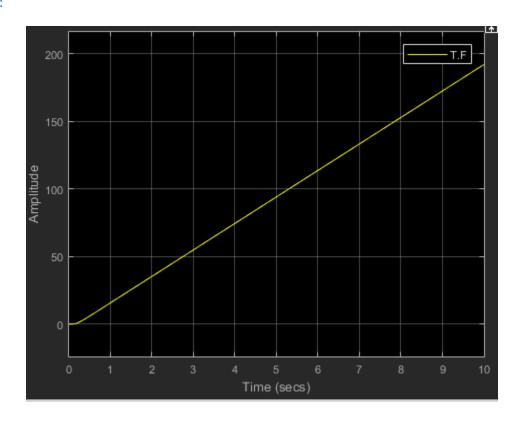
Simulation:



Hardware Schematic:

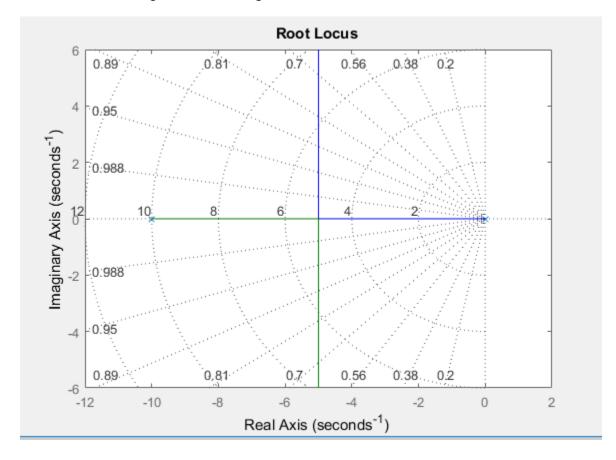


Result:



Comments:

• According to root locus diagram its %OS didn't reached 10%.



Stability Design via Routh-Hurwitz

Objectives:

1. Find out the range of gain in which system is stable.

$$G(s) = \frac{0.25K(s+0.435)}{s^4+3.456s^3+3.457s^2+0.719s+0.0416}$$

Theory:

$$T(s) = \frac{G(s)}{1+G(s)}$$

$$= \frac{\frac{0.25K(s+0.435)}{s^4+3.456s^3+3.457s^2+0.719s+0.0416}}{1+\frac{0.25K(s+0.435)}{s^4+3.456s^3+3.457s^2+0.719s+0.0416}}$$

$$= \frac{0.25K(s+0.435)}{s^4+3.456s^3+3.457s^2+(0.719+0.25K)s+(0.0416+0.109K)}$$

From s^2 the value of K, where over-all answer should be in +ve

$$11.228 - 0.25K = 0$$

$$K = 44.91$$

$$-\infty < K < 44.91$$

From s^1 the value of K, where over-all answer should be in +ve

Quadratic equation so, K = -4.685 and 25.87

For +ve numerator -4.685 < K < 25.87

From s^0 the value of K, where over-all answer should be in +ve

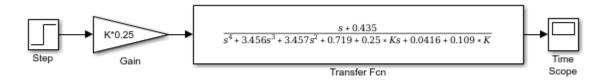
$$0.144 + 0.377K = 0$$

$$K = -0.3819$$

$$-0.3819 < K < \infty$$

Over-all System Stability lies b/w - 0.3819 < K < 25.87

Simulation:

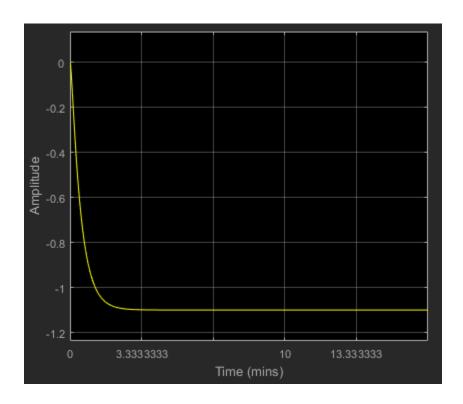


Hardware Schematic:

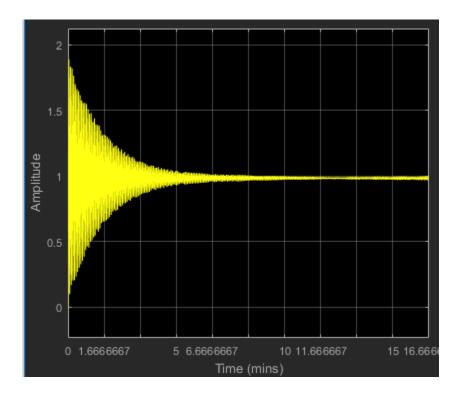
No hardware for this lab.

Result:

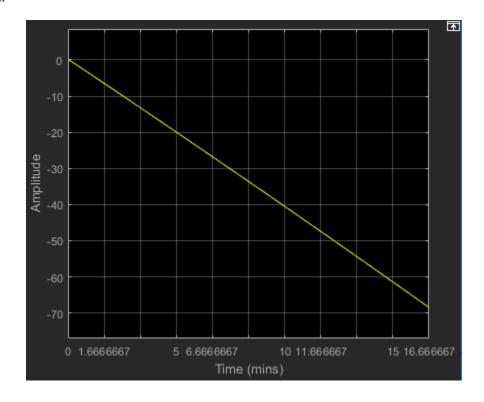
$$K = -0.2$$
:



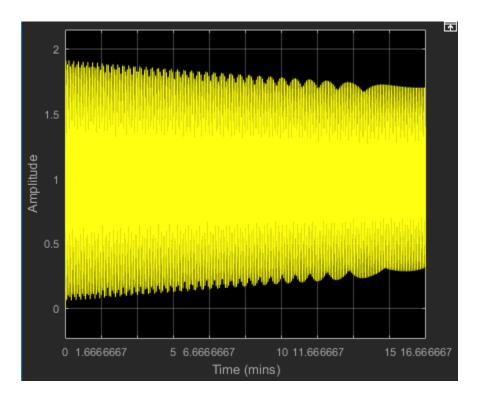
K = 25:



K = -0.382:



K = 25.87:



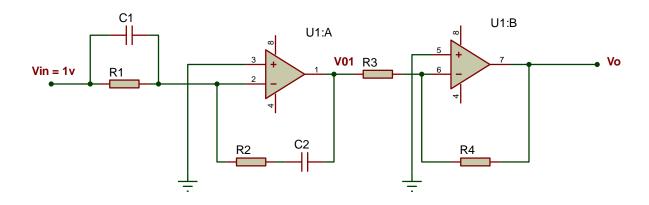
Comments:

- System was stable when K value lie b/w -0.382 to 25.87.
- When K value is less than or equal to -0.382 and great than or equal to 25.87 then system became unstable.

Operational Amplifier

Objectives:

1. Design the following circuit for maximum DC gain =20, Kp = 5, Ki = 0.9 & Kd = 1.6.



Theory:

Modeling:

$$\begin{split} \frac{\textit{Vo1}}{\textit{Vin}} &= -\frac{\textit{Z2(s)}}{\textit{Z1(s)}} \\ 1 \, / \, Z_1(s) &= C_1 S + 1 \, / \, R_1 = (1/C_2 S) \\ Z_1(s) &= R_1 \, / \, (1 + R_1 C_1 S) \\ Z_2(s) &= \left. (1 + R_2 C_2 S) \, / \, C_2 S \right. \\ \frac{\textit{Vo1}}{\textit{Vin}} &= -\left. (R_1 R_2 C_1 C_2 S^2 + (R_1 C_1 + R_2 C_2) S + 1) \, / \, (R_1 C_2 S) \right. \\ \frac{\textit{Vo}}{\textit{Vo1}} &= -\frac{\textit{Z4(s)}}{\textit{Z3(s)}} \\ \frac{\textit{Vo}}{\textit{Vo1}} &= -R_4 \, / \, R_3 \end{split}$$

In form of Kp, Ki, Kd

$$T.F = Gain (Kp + Ki/S + KdS)$$

Dc gain = R_4

$$Kp = (R_1C_1 + R_2C_2) / (R_3R_1C_2)$$
 eq. (a)

$$Ki/S = 1 / (R_3R_1C_2S)$$
 eq. (b)

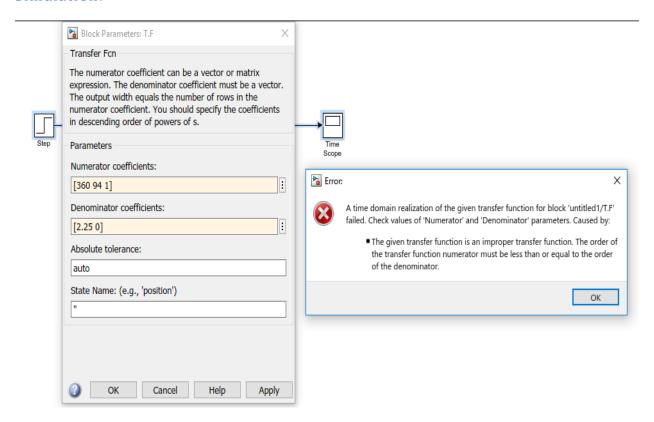
$$KdS = (R_2C_1S) / R_3$$
 eq. (c)

Required:

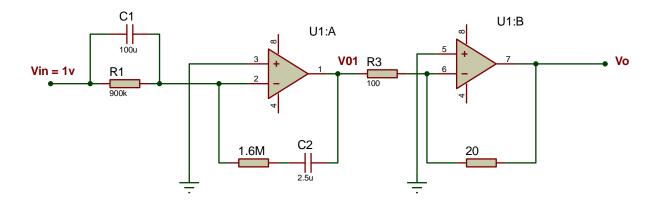
- Dc Gain = 20
- Kp =5
- Ki =0.9
- Kd = 1.6

 $R_1 = 10k \text{ (ohm)}; R_2 = 1.6M \text{ (ohm)}; R_3 = 100 \text{ (ohm)}; R_4 = 20 \text{ (ohm)}; C_1 = 100x10-6F; C_2 = 2.5uF; ei= 1volt$

Simulation:



Hardware Schematic:



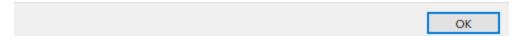
Result:





A time domain realization of the given transfer function for block 'untitled1/T.F' failed. Check values of 'Numerator' and 'Denominator' parameters. Caused by:

• The given transfer function is an improper transfer function. The order of the transfer function numerator must be less than or equal to the order of the denominator.



Comments:

• According to equation a, b and c different values are required for R₁, C₂ etc. This logic is wronged.

Steady-State Error

Objectives:

1. Find the steady-state error for the inputs of 5u(t) (Step Input), 5tu(t) (Ramp Input).

$$G(s) = \frac{120(s+2)}{(s+3)(s+4)}$$

Theory:

SSE for Step Input:

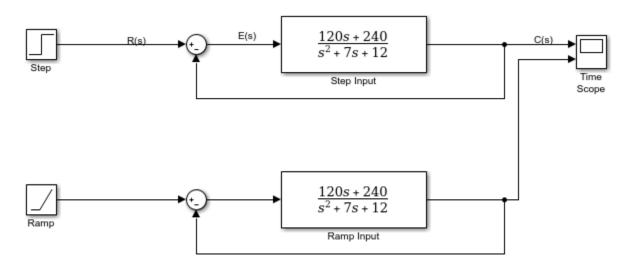
$$e(\infty) = e_{\text{step}}(\infty) = \frac{5}{(1 + \lim_{s \to 0} G(s))}$$
$$e_{\text{step}}(\infty) = e(\infty) = \frac{5}{21}$$

SSE for Ramp Input:

$$e(\infty) = e_{ramp}(\infty) = 5/\left(\lim_{s \to 0} G(s)\right)$$

$$e_{\text{step}}(\infty) = e(\infty) = 5/0 = \infty$$

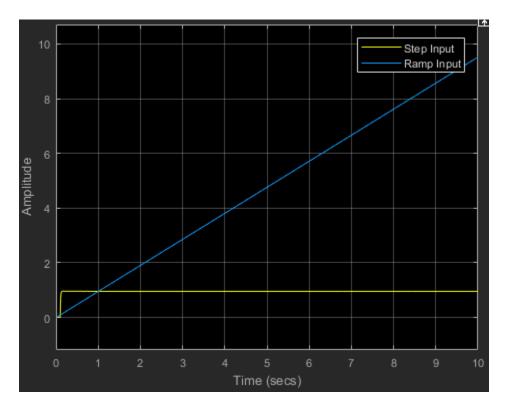
Simulation:



Hardware Schematic:

No hardware for this lab.

Result:



Comments:

• For ramp Input SSE of T.F approaches to infinity.

Design a Lag Compensator

Objectives:

1. Improve SSE by a factor of 10 if system is operating with damping ratio of 0.174.

$$G(s) = \frac{1}{(s+1)(s+2)(s+10)}$$

Theory:

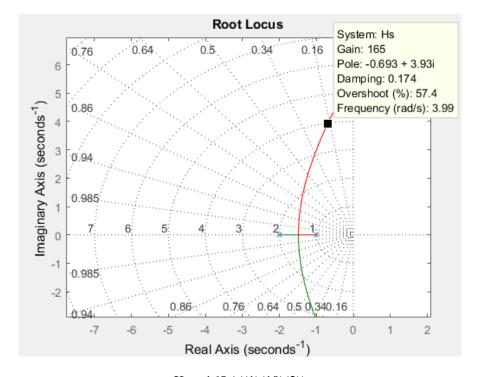
Root Locus:

>> num=[1];

>> den=[1 13 32 20];

>> Hs=tf(num,den)

>> rlocus(Hs)



$$K_p = 165 / ((1)(10)(2))$$

$$K_p = 8.25$$

SSE =
$$e(\infty) = 1 / (1 + K_p)$$

 $e(\infty) = 0.108$

Required SSE:

$$SSE_{req.} = e(\infty) / 10 = 0.0108$$

 $K_p = 91.6$

Compensator:

$$K_{comp.}$$
 / $K_{uncomp.}$ = z_c / p_c = $91.6/8.25$ = $11.1\,$

Let pc 0.001

$$Z_c = (0.001)(11.1) = 0.0111$$

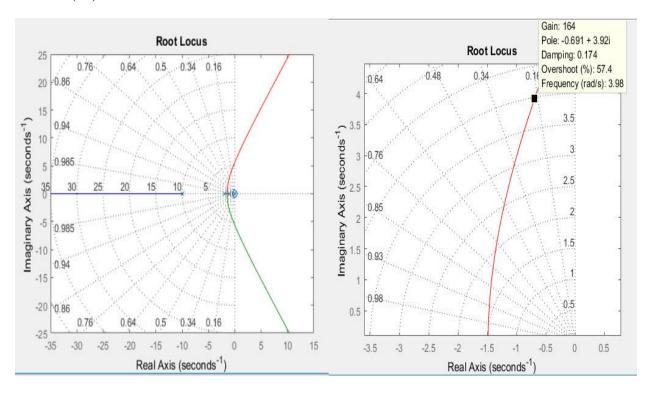
Root Locus:

>> num=[1 0.011];

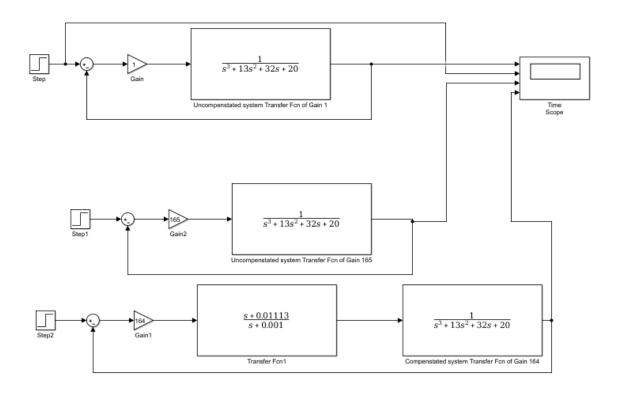
>> den=[1 13.001 32.013 20.032 0.0200];

>> Hs=tf(num,den)

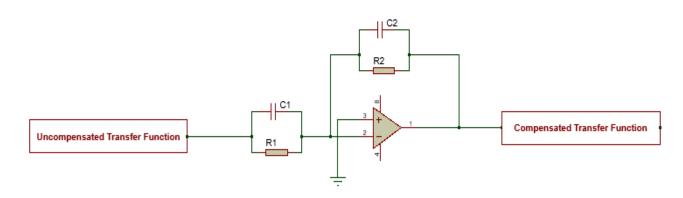
>> rlocus(Hs)



Simulation:



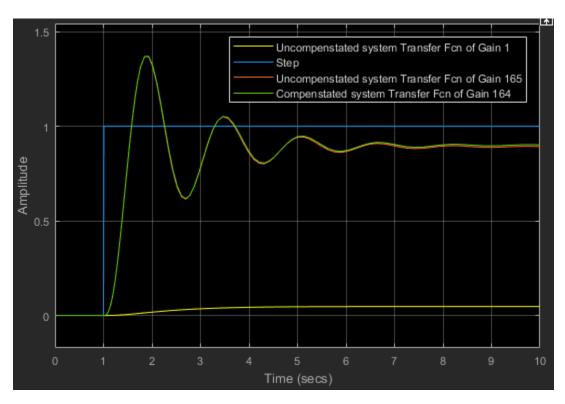
Hardware Schematic:



$$R_1C_1 < R_2C_2$$

$$Gain = K = - C_1 / C_2$$

Result:



Comments:

- Root locus diagram remain unchanged in Lag Compensation.
- Lag compensator didn't effect on transient response of any transfer function.
- It is used to improve SSE.

Design a Lead Compensator

Objectives:

1. Improve transient response by a factor of 2 if system is operating at 30% overshoot.

$$G(s) = \frac{k}{s(s+4)(s+6)}$$

Theory:

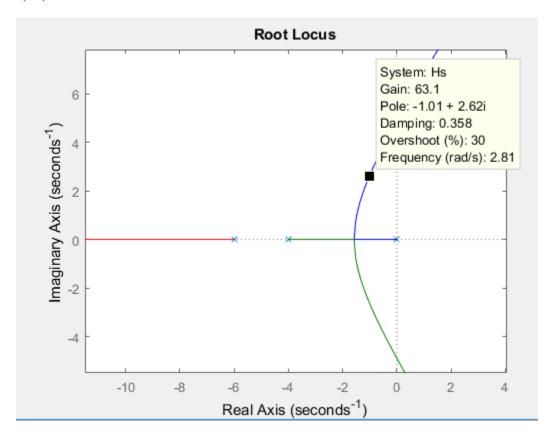
Root Locus:

>> num=[1];

>> den=[1 10 24 0];

>> Hs=tf(num,den)

>> rlocus(Hs)



$$a = \cos \theta$$

$$\theta = \cos^{-1}(3)$$

$$\theta = 110.98$$

Pole =
$$-1.01 + 2.62j$$

$$T_s = 4/1.01 = 3.96$$

Required T_s:

$$(Transient Resposne)_{req.} = T_s / 2 = 1.98$$

Real part =
$$6 G_d = 2.02$$

Img. Part =
$$-2.02$$
 (tan (110.98) = 5.3

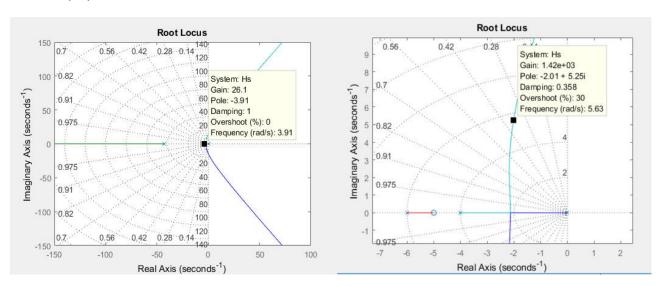
Compensator:

Let
$$z_c = 5$$

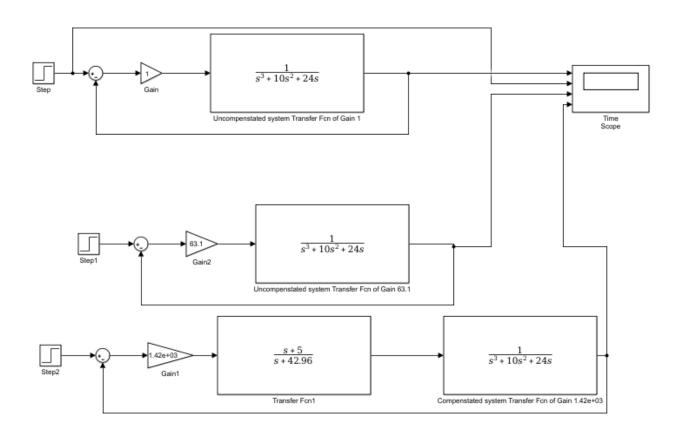
$$p_c = 42.96$$

Root Locus:

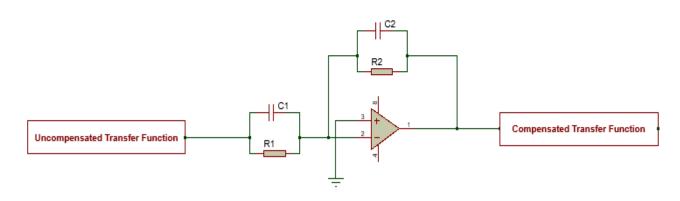
- >> num=[1 5];
- >> den=[1 52.96 453.6 1031.04 0];
- >> Hs=tf(num,den)
- >> rlocus(Hs)



Simulation:



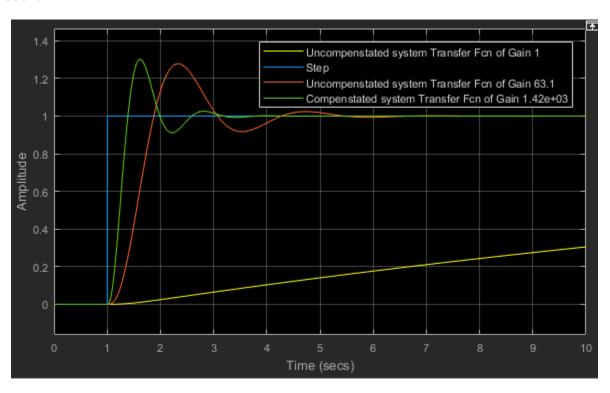
Hardware Schematic:



 $R_1C_1 > R_2C_2$

Gain = $K = -C_1 / C_2$

Result:



Comments:

- Root locus diagram changed in Lead Compensation.
- Lead compensator didn't effect on SSE of any transfer function.
- It is used to improve transient response of any transfer function.

Design a Lead-Lag Compensator

Objectives:

1. Improve transient response and SSE by a factor of 2 and 10 respectively if system is operating at 20% overshoot.

$$G(s) = \frac{k}{s(s+10)(s+6)}$$

Theory:

Lead Compensation

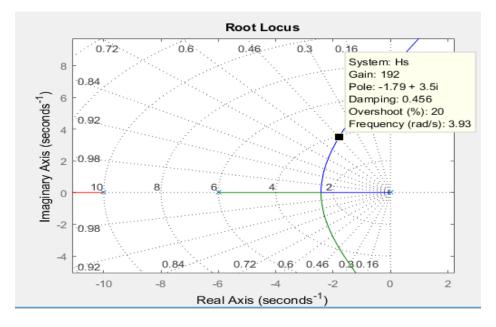
Root Locus:

>> num=[1];

>> den=[1 16 60 0];

>> Hs=tf(num,den)

>> rlocus(Hs)



$$3 = \cos \theta$$

$$\theta = \cos^{-1}(0.456)$$

$$\theta = 62.87$$

Pole =
$$-1.79 + 3.5j$$

$$T_s = 4/1.79 = 2.23$$

Required T_s:

$$(Transient Resposne)_{req.} = T_s / 2 = 1.117$$

Real part =
$$6 = 3.58$$

Img. Part =
$$3.58$$
 (tan $(62.87) = 6.987$

$$S = -3.58 + 6.987j$$

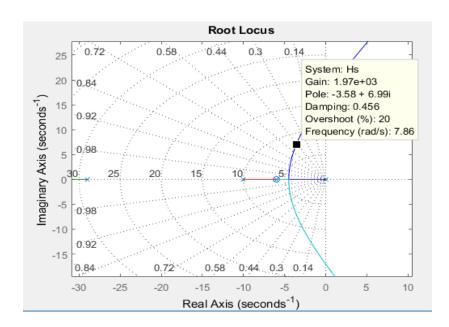
Compensator:

Let $z_c = -6$

$$p_c = -29.03$$

Root Locus:

- >> num=[1 6];
- >> den=[1 45.03 524.485 1741.8 0];
- >> Hs=tf(num,den)
- >> rlocus(Hs)



Lead Compensation

$$SSE = e(\infty) = 1 / K_v$$

$$K_v = 192 / 6(10) = 3.2$$

$$SSE = e(\infty) = 1 / 3.2 = 0.3125$$

Required SSE:

$$SSE_{req.} = e(\infty) / 10 = 0.03125$$
 (overall)

$$K_v$$
 (lead compensator) = 1977(6)/((29.03)(10)(6)) = 6.8

$$SSE = e(\infty) = 1/6.8 = 0.147$$

$$\frac{K(lead)}{K(uncomp)} = \frac{6.8}{3.2} = 2.12$$

Compensator:

$SSE_{req.} = 10 / 2.12 = 4.716$ (After Lead Compensation)

$$z_c / p_c = 4.716$$

Let $p_c = 0.01$

$$z_c = 0.04716$$

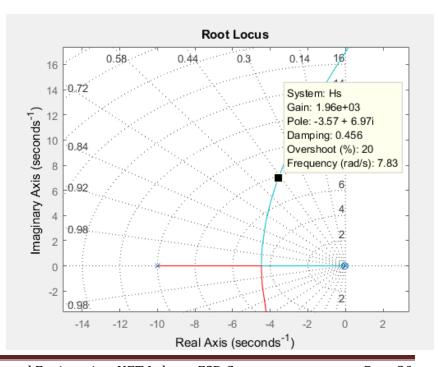
Root Locus:

>> num=[1 0.04716];

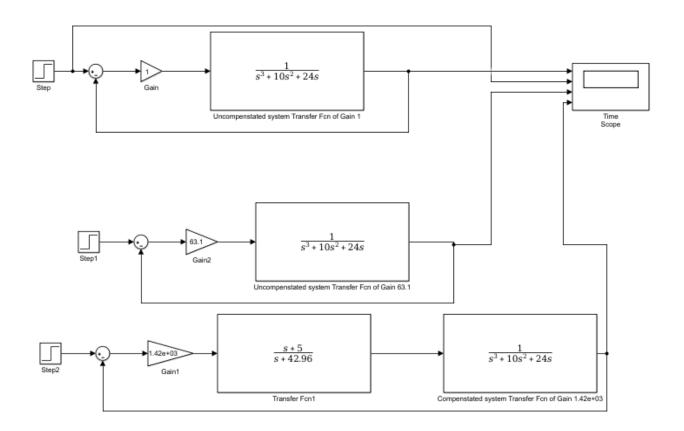
>> den=[1 39.04 290.69 2.903 0];

>> Hs=tf(num,den)

>> rlocus(Hs)

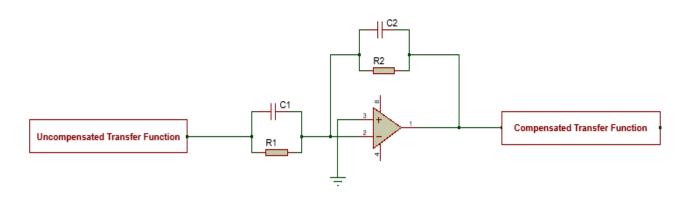


Simulation:



Hardware Schematic:

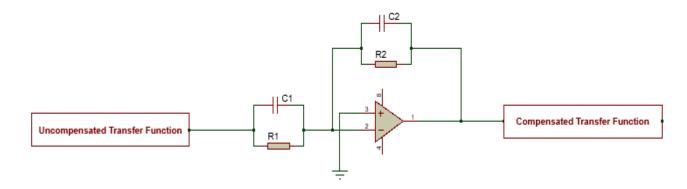
Lead Compensation:



 $R_1C_1 > R_2C_2$

$$Gain = K = -C_1/C_2$$

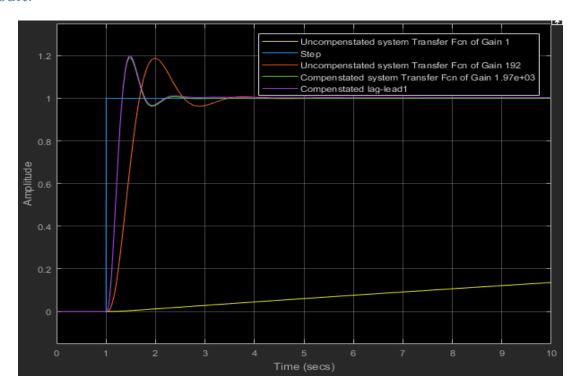
Lag Compensation:



$$R_1C_1 < R_2C_2$$

Gain =
$$K = -C_1 / C_2$$

Result:



Control System-I Lab - MCT-333L | Spring

Spring 2018

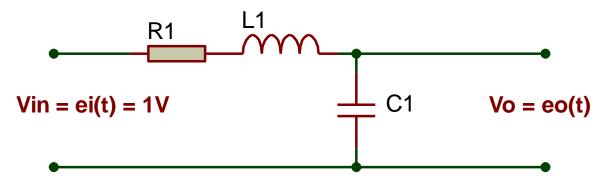
Comments:

- Root locus diagram changed in Lead Compensation.
- Lead compensator didn't effect on SSE of any transfer function.
- It is used to improve transient response of any transfer function.
- Root locus diagram remain unchanged in Lag Compensation.
- Lag compensator didn't effect on transient response of any transfer function.
- It is used to improve SSE.
- By lead-lag compensation we improved both transient response and SSE.

PID Controller

Objectives:

1. To model the following circuit and also use the PID controller for Under-Damped system



Theory:

Modeling:

$$\begin{split} LCS^{2}E_{o}(s) + RCSE_{o}(s) + E_{o}(s) &= E_{i}(s) \\ \frac{Eo(s)}{Ei(s)} &= \frac{1}{(LCS+RC)S+1} \\ \frac{Eo(s)}{Ei(s)} &= \frac{\frac{1}{LC}}{(\left(S+\frac{R}{L}\right)s+\frac{1}{LC})} \end{split}$$

Compare it with General T.F of 2st order equation T.F = $\omega_n^2 / (s^2 + 2\rho \omega_n s + \omega_n^2)$

$$a=R/L=2\rho\omega_n$$

$$\rho=a/(2\omega_n)$$

$$b=1/(LC)=\omega_n^2$$

$$0<\rho<1$$

Control System-I Lab - MCT-333L

$$R = 40 \text{ (ohm)}; C = 510x10-6F; L= 1H; ei= 1volt$$

$$\rho = 0.452$$

$$\omega_{n} = 44.28 \text{ rad/s}$$

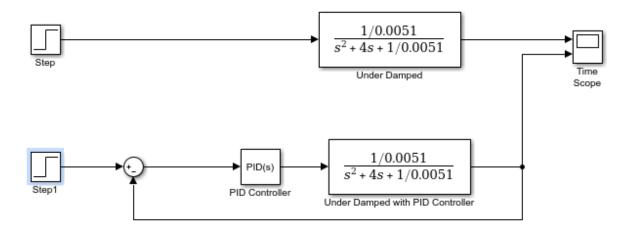
$$Tp = \frac{\pi}{\omega\sqrt{(1-\rho^{2})}} = 0.0795 \text{ s}$$

$$\%OS = e^{-\frac{\rho\pi}{\sqrt{1-\rho^{2}}}} \times 100 = 20.4\%$$

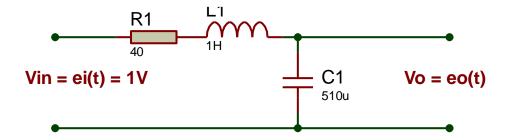
Required:

Tp =
$$\frac{Tp}{5.3}$$
 = 0.015 s
%OS = $e^{-\frac{\rho\pi}{\sqrt{1-\rho^2}}} \times 100 = 20.4\%$

Simulation:



Hardware Schematic:



Result:

at Kp = 2.3, Ki = 10 & Kd = 0.7



Comments:

• By PID controller we can control the transient response as well as SSE, Tr, Ts etc.